WHAT IS CLAIMED IS:

- 1. A liquid crystal display device comprising:
- a first substrate having a common electrode;
- a second substrate having an active area;
- a seal pattern formed peripherally to said active area, and between said first substrate and said second substrate:
- a liquid crystal layer between said first substrate and said second substrate, and on the active area; and
 - an electrode pattern adjacent to said seal pattern and outside said active area.
- The device of claim 1, wherein said electrode pattern is between said seal pattern and said second substrate.
 - 3. The device of claim 1, wherein said second substrate comprises:
 - data lines and gate lines arranged in a matrix shape to define pixel areas;
 - a TFT at an intersection of a data line and a gate line;
 - a protective film on the TFT; and
 - a pixel electrode on said protective film.
- The device of claim 3, wherein the electrode pattern is between said seal pattern and said protective film.
- The device of claim 3, wherein said electrode pattern is the same material as said pixel electrode.

- The device of claim 3, wherein said electrode pattern is formed at the same time as said pixel electrode.
- The device of claim 1, wherein said electrode pattern forms an electric field with said common electrode.
- The device of claim 1, wherein said electrode pattern is applied with a constant DC bias voltage.
- 9. The device of claim 1, wherein said electrode pattern is applied with a voltage which is stepped down from a common voltage applied to said common electrode.
- 10. The device of claim 1, wherein said electrode pattern is applied with a voltage which is reversed in polarity from a common voltage applied to said common electrode.
 - 11. A liquid crystal display device comprising:
 - a first substrate having a common electrode;
 - a second substrate having an active area;
- a seal pattern formed peripherally to said active area between said first substrate and said second substrate, and having projected corner portions; and
- a liquid crystal layer between said first substrate and said second substrate in said active area.

- 12. The device of claim 11, further comprising an electrode pattern on a portion of said second substrate adjacent to said seal pattern outside of said active area.
- 13. The device of claim 12, wherein said electrode pattern is between said seal pattern and said second substrate.
 - 14. The device of claim 11, wherein said second substrate comprises:

data lines and gate lines arranged in a matrix shape to define pixel areas;

- a TFT at an intersection of a data line and a gate line;
- a protective film on the TFT; and
- a pixel electrode on said protective film.
- 15. The device of claim 14, wherein said electrode pattern is between said seal pattern and said protective film.
- 16. The device of claim 14, wherein said electrode pattern is made of the same material as said pixel electrode.
- 17. The device of claim 14, wherein said electrode pattern is formed at the same time as said pixel electrode.
- 18. The device of claim 12, wherein said electrode pattern forms an electric field with said common electrode.

- 19. The device of claim 12, wherein said electrode pattern is applied with a constant DC bias voltage.
- 20. The device of claim 12, wherein said electrode pattern is applied with a voltage which is stepped down from a common voltage applied to said common electrode.
- 21. The device of claim 12, wherein said electrode pattern is applied with a voltage which is reversed in polarity from a common voltage applied to said common electrode.